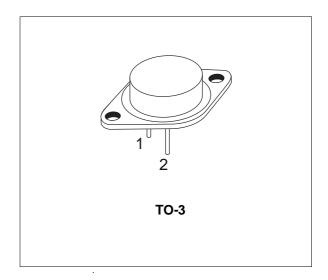


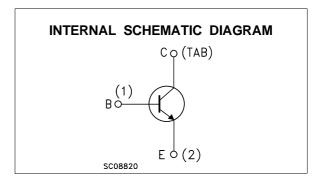
# HIGH CURRENT NPN SILICON TRANSISTOR

- STMicroelectronics PREFERRED SALESTYPE
- NPN TRANSISTOR

#### **DESCRIPTION**

The BUR51 is a silicon Multiepitaxial Planar NPN transistor in modified Jedec TO-3 metal case, intented for use in switching and linear applications in military and industrial equipment.





### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)	300	V
$V_{CEO}$	Collector-Emitter Voltage (I <sub>B</sub> = 0)	200	V
$V_{EBO}$	Emitter-Base Voltage (I <sub>C</sub> = 0)	10	V
Ic	Collector Current	60	Α
I <sub>CM</sub>	Collector Peak Current (tp = 10 ms)	80	Α
$I_{B}$	Base Current	16	Α
$P_{tot}$	Total Dissipation at T <sub>c</sub> ≤ 25 °C	350	W
$T_{stg}$	Storage Temperature	-65 to 200	°C
Tj	Max. Operating Junction Temperature	200	°C

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### THERMAL DATA

## **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25 °C unless otherwise specified)

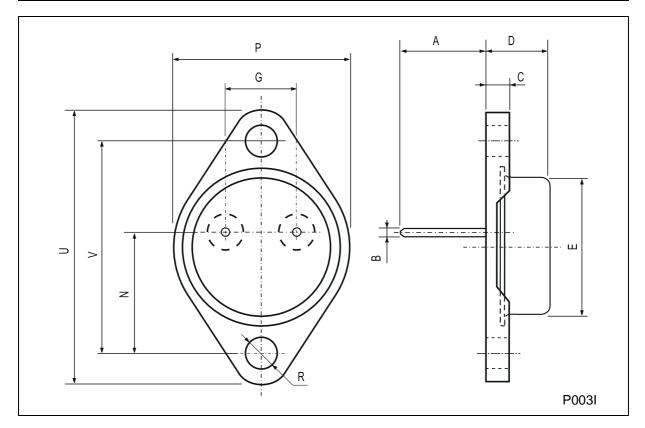
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector Cut-off Current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 300 V V <sub>CB</sub> = 300 V	T <sub>c</sub> = 125 °C			0.2	mA mA
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	V <sub>CE</sub> =200 V				1	mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 7 V				0.2	μΑ
V <sub>CEO(sus)</sub> *	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 200 mA		200			V
V <sub>EBO</sub>	Emitter-base Voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 10 mA		10			V
$V_{CE(sat)^*}$	Collector-emitter Saturation Voltage	I <sub>C</sub> = 30 A I <sub>C</sub> = 50 A	$I_B = 2 A$ $I_B = 5 A$		0.9	1 1.5	V V
V <sub>BE(sat)*</sub>	Base-emitter Saturation Voltage	I <sub>C</sub> = 30 A I <sub>C</sub> = 50 A	$I_B = 2 A$ $I_B = 5 A$		1.55	1.8 2	V V
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 5 A I <sub>C</sub> = 50 A	$V_{CE} = 4 V$ $V_{CE} = 4 V$	20 15		100	
I <sub>s/b</sub>	Second Breakdown Collector Current	V <sub>CE</sub> = 20 V	t = 1 s	17.5			Α
f⊤	Transition-Frequency	I <sub>C</sub> = 1 A f = 1 MHz	V <sub>CE</sub> = 5 V	10	16		MHz
ton	Turn-on Time	I <sub>C</sub> = 50 A V <sub>CC</sub> = 100 V	$I_{B1} = 5 A$		0.35	1	μs
t <sub>s</sub> t <sub>f</sub>	Storage Time Fall Time	I <sub>C</sub> = 50 A I <sub>B2</sub> = -5 A	$I_{B1} = 5 A$ $V_{CC} = 100 V$		0.9 0.24	2 0.6	μs μs
	Clamped E <sub>s/b</sub> Collector Current	V <sub>clamp</sub> = 200 V	L = 500 μH	50			А

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

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## TO-3 (I) MECHANICAL DATA

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	11	11.7	13.1	0.433	0.461	0.516	
В	1.45	1.5	1.6	0.057	0.059	0.063	
С	2.7		2.92	0.106		0.115	
D	8.9		9.4	0.350		0.370	
Е	19		20	0.748		0.787	
G	10.7	10.9	11.1	0.421	0.429	0.437	
N	16.5	16.9	17.2	0.650	0.665	0.677	
Р	25		26	0.984		1.024	
R	3.88		4.2	0.153		0.165	
U	38.5		39.3	1.516		1.547	
V	30	30.14	30.3	1.181	1.187	1.193	



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